## NSN 5961-00-247-2395



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-247-2395 **Inclosure Material:** Metal **Overall Length:** 0.666 inches **Overall Diameter:** 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.430 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 19315-1941931 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf

**Terminal Type And Quantity:** 

4 tab, solder lug

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0